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Amendt. BCN
Y. Polinsky
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DOCKET NO: 214258US2S

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :

MICHIHARU MATSUI ET AL : EXAMINER: TRAN, T..

SERIAL NO: 09/956,986 :

FILED: SEPTEMBER 21, 2001 : GROUP ART UNIT: 2811

FOR: NONVOLATILE
SEMICONDUCTOR MEMORY DEVICE
HAVING ELEMENT ISOLATING
REGION OF TRENCH TYPE AND
METHOD OF MANUFACTURING THE
SAME

AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated May 9, 2003, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 5 of this paper.

Amendments to the Drawings begin on page 23 of this paper and include replacements sheets.

Remarks begin on page 24 of this paper.

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